

# PJD25N10A-AU

## 100V N-Channel Enhancement Mode MOSFET

**Voltage** 100 V **Current** 25 A

### Features

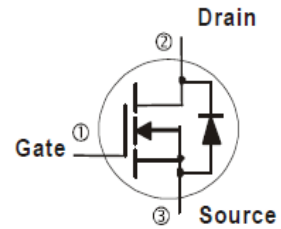
- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@15A < 55m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_D@10A < 60m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.3217 grams



TO-252AA



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	100	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	
Continuous Drain Current <sup>(Note 4)</sup>	$T_C=25^\circ\text{C}$	$I_D$	25	A
	$T_C=100^\circ\text{C}$		15	
Pulsed Drain Current <sup>(Note 1)</sup>	$T_C=25^\circ\text{C}$	$I_{DM}$	100	
Power Dissipation	$T_C=25^\circ\text{C}$	$P_D$	60	W
	$T_C=100^\circ\text{C}$		24	
Continuous Drain Current <sup>(Note 4)</sup>	$T_A=25^\circ\text{C}$	$I_D$	4.4	A
	$T_A=70^\circ\text{C}$		3.5	
Power Dissipation	$T_A=25^\circ\text{C}$	$P_D$	2	W
	$T_A=70^\circ\text{C}$		1.3	
Single Pulse Avalanche Energy <sup>(Note 6)</sup>		$E_{AS}$	31	mJ
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	$^\circ\text{C}$
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Case	$R_{\theta JC}$	2.1	$^\circ\text{C/W}$
	Junction to Ambient	$R_{\theta JA}$	62.5	

- Limited only By Maximum Junction Temperature

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## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	100	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1	1.5	2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =15A	-	37	55	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =10A	-	38	60	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =80V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	-	-	±100	nA
<b>Dynamic</b> (Note 7)						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =80V, I <sub>D</sub> =15A, V <sub>GS</sub> =10V(Note 2,3)	-	61	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	8.8	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	11	-	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1MHZ	-	3601	-	pF
Output Capacitance	C <sub>oss</sub>		-	133	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	65	-	
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =50V, I <sub>D</sub> =15A, V <sub>GS</sub> =10V, R <sub>G</sub> =3.3Ω(Note 2,3)	-	16	-	ns
Turn-On Rise Time	t <sub>r</sub>		-	50	-	
Turn-Off Delay Time	t <sub>d(off)</sub>		-	64	-	
Turn-Off Fall Time	t <sub>f</sub>		-	18	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>	---	-	-	25	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.7	1.2	V

**NOTES :**

1. Pulse width ≤ 300us, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> = 25°C.
4. The maximum current rating is package limited.
5. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
6. The test condition is L=0.1mH, I<sub>AS</sub>=25A, V<sub>DD</sub>=25V, V<sub>GS</sub>=10V.
7. Guaranteed by design, not subject to production testing.

# PJD25N10A-AU

## TYPICAL CHARACTERISTIC CURVES

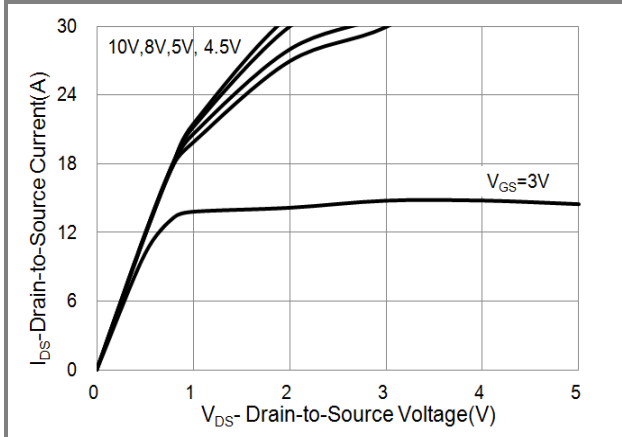


Fig.1 Output Characteristics

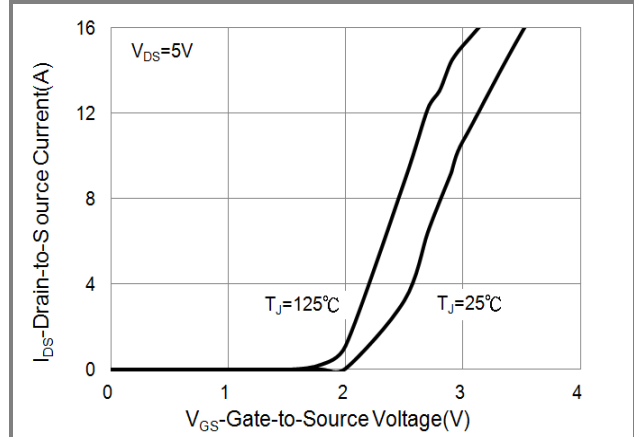


Fig.2 Transfer Characteristics

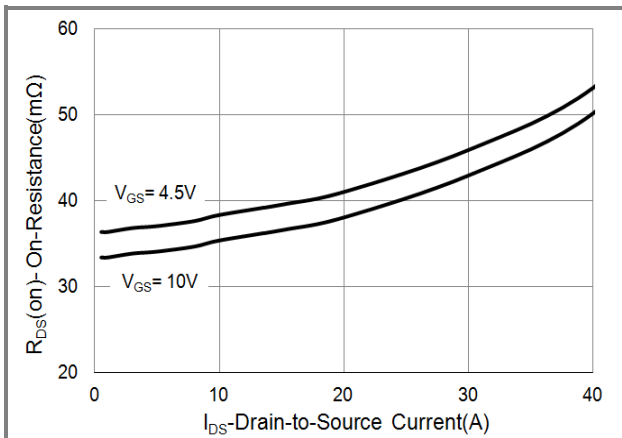


Fig.3 On-Resistance vs. Drain Current

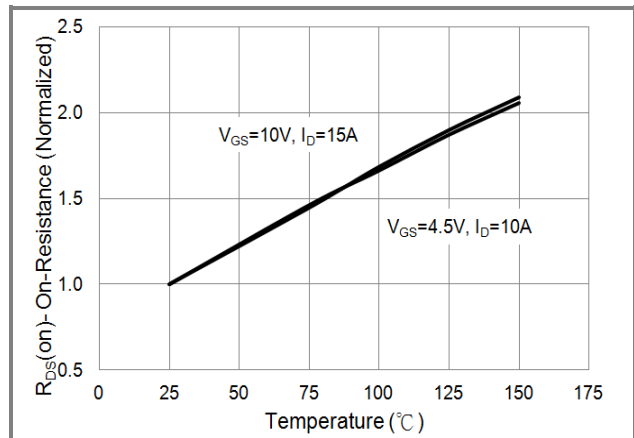


Fig.4 On-Resistance vs. Junction temperature

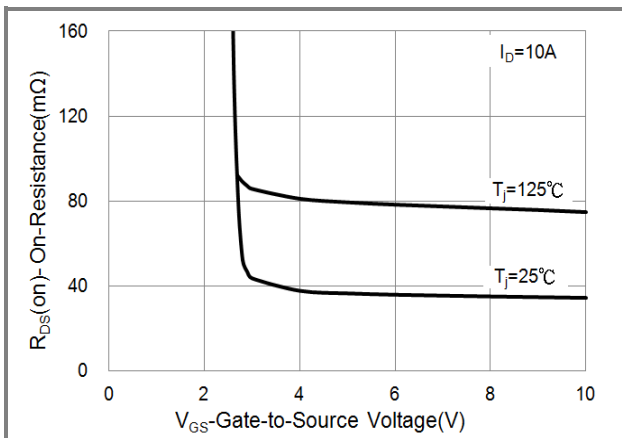


Fig.5 On-Resistance Variation with  $V_{GS}$

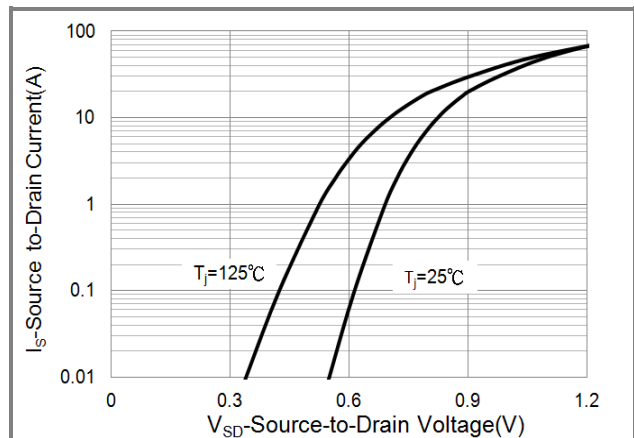


Fig.6 Source-Drain Diode Forward Voltage

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## TYPICAL CHARACTERISTIC CURVES

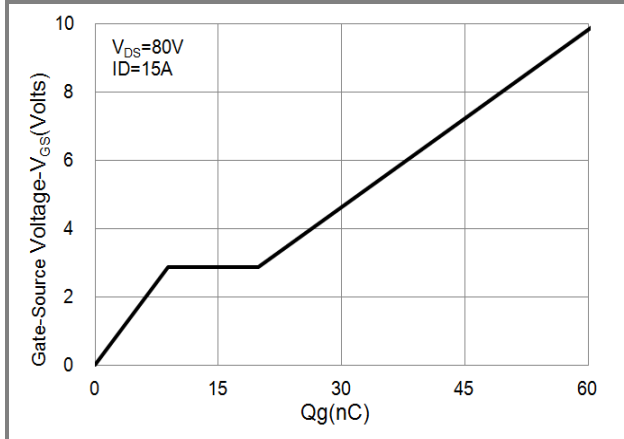


Fig.7 Gate-Charge Characteristics

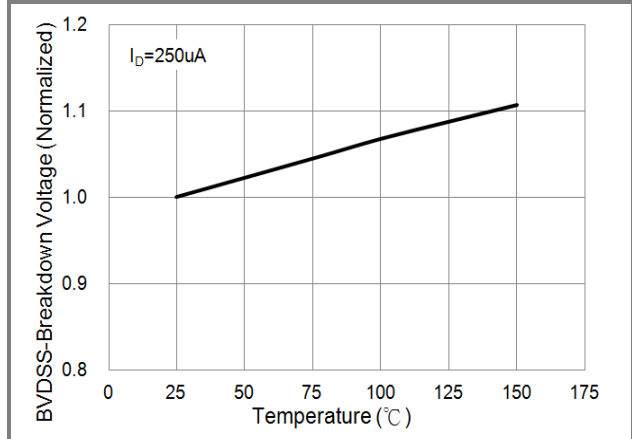


Fig.8 Breakdown Voltage Variation vs. Temperature

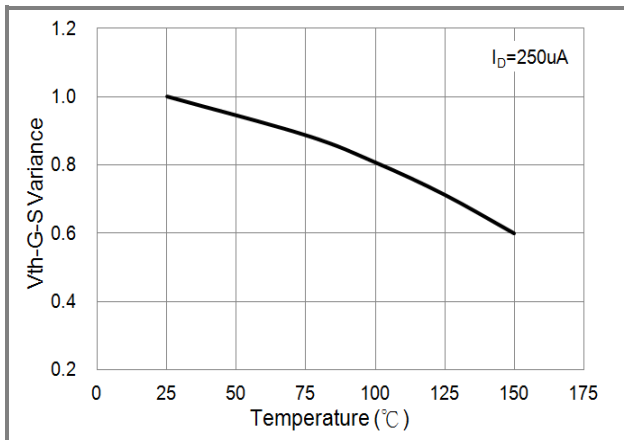


Fig.9 Threshold Voltage Variation with Temperature

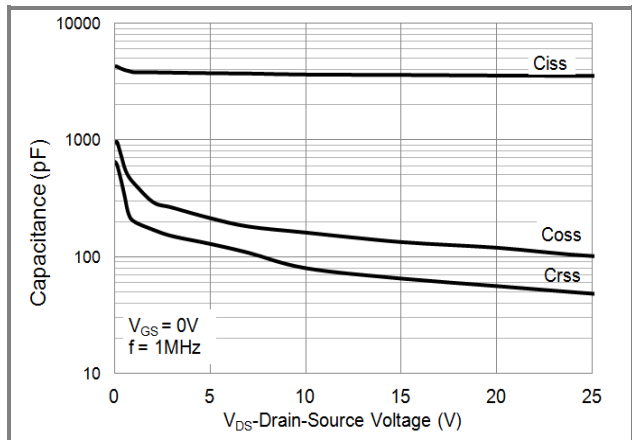


Fig.10 Capacitance vs. Drain-Source Voltage

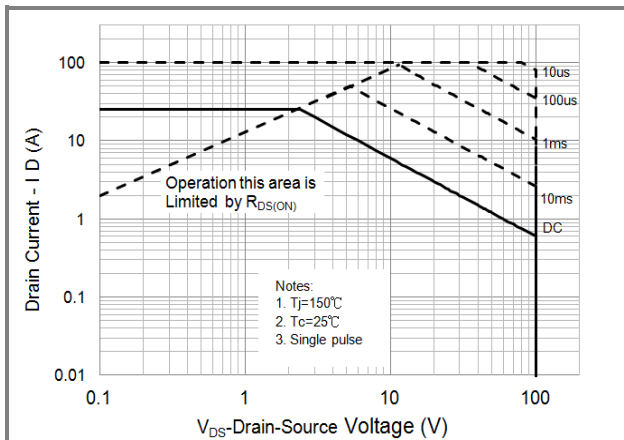


Fig.11 Maximum Safe Operating Area

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## TYPICAL CHARACTERISTIC CURVES

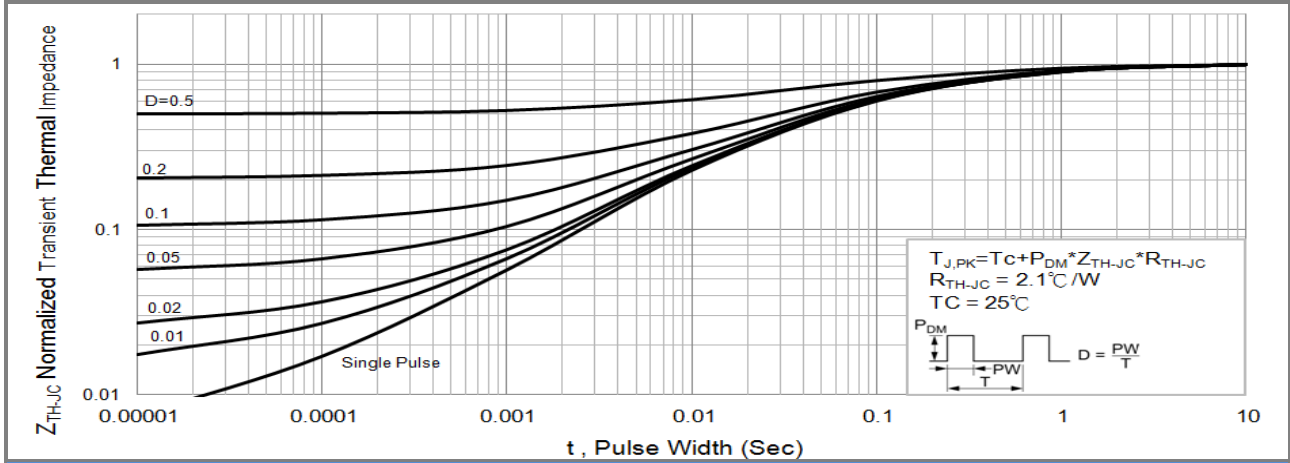


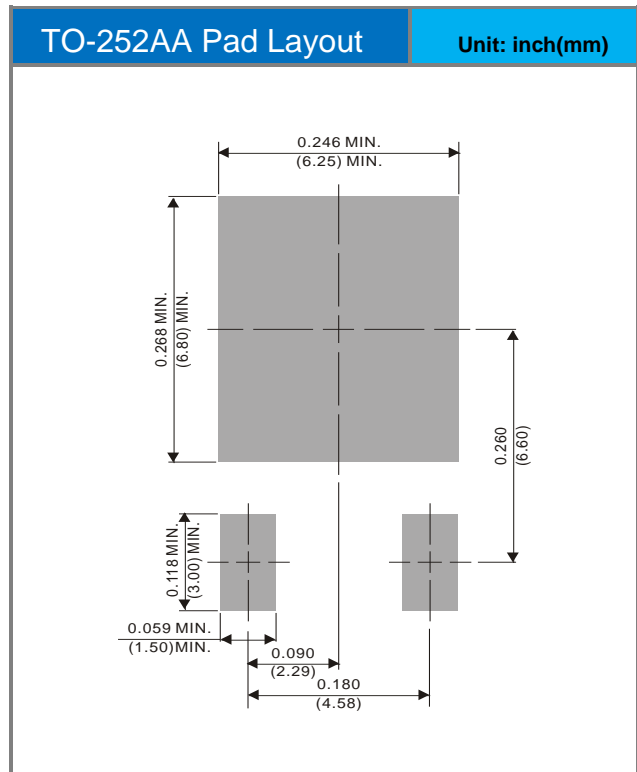
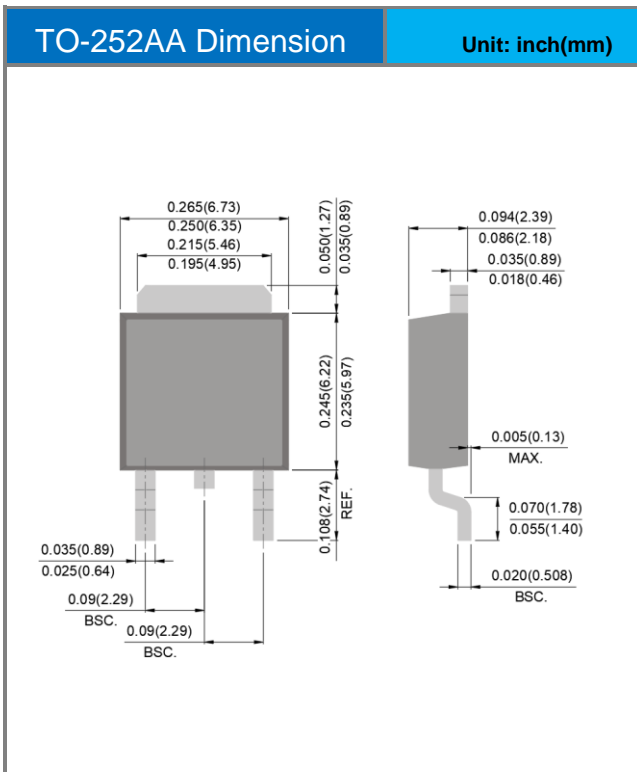
Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

# PJD25N10A-AU

## Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJD25N10A-AU	TO-252AA	3K pcs / 13" reel	D25N10A

## Packaging Information & Mounting Pad Layout



## PJD25N10A-AU

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